



SPECIFICATION

• Supplier : Samsung electro-mechanics • Samsung P/N : CL31B106KQHNNNF

• Product : Multi-layer Ceramic Capacitor • Description : CAP, 10 µF, 6.3V, ±10%, X7R, 1206

A. Samsung Part Number

<u>CL</u> <u>31</u> <u>B</u> <u>106</u> <u>K</u> <u>Q</u> <u>H</u> <u>N</u> <u>N</u> <u>N</u> <u>F</u> ① ② ③ ④ ⑤ ⑥ ⑦ ⑧ ⑨ ⑩ ⑪

1	Series	Samsung Multi-layer Ceramic Capacitor									
2	Size	1206 (in	ch co	de)	L:	3.2	± 0.2	mm	W:	1.6 ± 0.2	mm
3	Dielectric	X7R				8	Inner e	lectrode	N	i	
4	Capacitance	10 μF					Termin	ation	С	u	
(5)	Capacitance	±10 %					Plating		S	n 100%	(Pb Free)
	tolerance					9	Produc	t	N	ormal	
6	Rated Voltage	6.3 V				10	Special		R	eserved for	future use
7	Thickness	1.6 ± 0).2 r	mm		11)	Packag	jing	Е	mbossed T	ype,13"reel(8,000ea)

B. Samsung Reliability Test and Judgement condition

	Performance	Test condition						
Capacitance	Within specified tolerance	1kHz±10% 1.0±0.2Vrms						
Tan δ (DF)	0.1 max.							
Insulation	More than 100Mohm⋅ <i>μ</i> Γ	Rated Voltage 60~120 sec.						
Resistance								
Appearance	No abnormal exterior appearance	Visual inspection						
Withstanding	No dielectric breakdown or	250% of the rated voltage						
Voltage	mechanical breakdown							
Temperature	X7R							
Characteristics	(From -55°C to 125°C, Capacitance change should be within ±15%)							
Adhesive Strength	No peeling shall occur on the	500g·F, for 10±1 sec.						
of Termination	terminal electrode							
Bending Strength	Capacitance change: within ±12.5%	Bending to the limit (1mm)						
		with 1.0mm/sec.						
Solderability	More than 75% of terminal surface	SnAg3.0Cu0.5 solder						
	is to be soldered newly	245±5℃, 3±0.3sec.						
		(preheating: 80~120°C for 10~30sec.)						
Resistance to	Capacitance change: within ±7.5%	Solder pot : 270±5℃, 10±1sec.						
Soldering heat	Tan δ, IR : initial spec.							

	Performance	Test condition				
Vibration Test	Capacitance change : within ±5%	Amplitude : 1.5mm				
	Tan δ, IR : initial spec.	From 10Hz to 55Hz (return : 1min.)				
		2hours × 3 direction (x, y, z)				
Moisture	Capacitance change: within ±12.5%	With rated voltage				
Resistance	Tan δ : 0.125 max	40±2℃, 90~95%RH, 500+12/-0 hours				
	IR : More than 12.5MΩ· <i>μ</i> F					
High Temperature	Capacitance change: within ±12.5%	With 150% of the rated voltage				
Resistance	Tan δ : 0.125 max	Max. operating temperature				
	IR : More than 25ΜΩ·μF					
		1000+48/-0 hours				
Temperature	Capacitance change: within ±7.5%	1 cycle condition				
Cycling	Tan δ, IR : initial spec.	Min. operating temperature → 25 °C				
		$ ightarrow$ Max. operating temperature $ ightarrow$ 25 $^{\circ}\!$				
		5 cycles test				

C. Recommended Soldering method :

Reflow (Reflow Peak Temperature : 260+0/-5 $^{\circ}$ C, 10sec. Max)

^{*} For more detailed Specification, Please refer to the Samsung MLCC catalogue.